

PRELIMINARY April 1987

# DM54ALS390/DM74ALS390 Dual 4-Bit Decade Counters

### **General Description**

Each of these monolithic counters contains eight masterslave flip-flops and additional gating to implement two independent four bit counters in a single package.

To use their maximum count length, the B input is connected to the QA output. The input count pulses are applied to input A and the outputs are as described in the appropriate truth table. A symmetrical divide-by-ten count can be obtained by connecting the QD output to the A input and applying the input count to the B input.

### **Features**

- Switching specifications at 50 pF
- Switching specifications guaranteed over full temperature and  $V_{\mbox{CC}}$  range
- Advanced oxide-isolated, ion-implanted Schottky TTL process
- Individual clocks for A and B flip-flops provide dual divide-by-2 and divide-by-5 counters

Direct clear for each 4-bit counter

Connection Diagr		Function T	BCD Co	unt Sequ e Note 2		
CLKA1	16 VCC	Count		Output		
CLR1 -2	15 CLKA2	Count	QD	QC	QB	QA
QA1	$\frac{14}{17}$ CLR2	0	L	L	L	L
CLK1B	13 12 12	1	L	L	L	н
QB1 5	12 11 11	2	L	L	н	L
QC1 - 7	11 QB2 10 QC2	3	L	L	н	н
QD1		4	L	н	L	L
GND -	9 QD2	5	L	н	L	н
	TL/F/9169-1	6	L	н	Н	L
	5390J, DM74ALS390M or LS390N	7	L	н	н	н
See NS Package Numb	8	н	L	L	L	
	,,	9	н	L	L	н
				uinary (5 e Note 3	)	
		Count	Output			0.0
				QD		QB
		0	L .	L .	L	L
		1	L	L	L	H
		2	L	L	Н	L
		3	L	L	Н	Н
		4	L	н	L	L
		5	н	L	L	L
		6	Н	L	L	Н
		7	н	L	Н	L
		8	н	L	Н	н
		9	Н	н	L	L
		Note 2: Outpu Note 3: Outpu H = High Log	t QD is cor	nnected to	nput A for	

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DM54ALS390/DM74ALS390 Dual 4-Bit Decade Counters

Absolute Maximum Rating If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	
DM54ALS	-55°C to +125°C
DM74ALS	0°C to +70°C
Storage Temperature Range	$-65^{\circ}$ C to $+150^{\circ}$ C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaran-teed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

## **Recommended Operating Conditions**

Symbol	Parameter		D	DM54ALS390			DM74ALS390		
Cymbol			Min	Nom	Max	Min	Nom	Max	Units
V <sub>CC</sub>	Supply Voltage		4.5	5	5.5	4.5	5	5.5	V
V <sub>IH</sub>	High Level Input Voltage		2			2			V
VIL	Low Level Input Voltage				0.7			0.8	V
I <sub>OH</sub>	High Level Output Current				-0.4			-0.4	mA
I <sub>OL</sub>	Low Level Output Current				4			8	mA
<b>f</b> COUNT	Count Frequency	A Input	0			0			MHz
		B Input	0			0			1011 12
t <sub>W</sub>	Pulse Width	A Input High							
		A Input Low							ns
		B Input High							115
		Clear High							
t <sub>SU</sub>	Clear Inactive-State Setup Time								ns
T <sub>A</sub>	Free Air Operating	Free Air Operating Temperature			125	0		70	°C

# Electrical Characteristics over recommended free air temperature range

Symbol	Parameter	Test Conditions		Min	Тур	Max	Units
V <sub>IC</sub>	Input Clamp Voltage	$V_{CC} = Min, I_I = -18 \text{ mA}$				-1.5	V
V <sub>OH</sub>	High Level Output Voltage	$V_{CC} = 4.5V$ to 5.5V, $I_{OH} = -0.4$ mA		V <sub>CC</sub> – 2			V
V <sub>OL</sub>	Low Level Output Voltage	$V_{CC} = Min$	54/74ALS I <sub>OL</sub> = 4 mA		0.25	0.4	v
			74ALS I <sub>OL</sub> = 8 mA		0.35	0.5	
lj –	Input Current at Max, $V_I = 7V$		Clear			100	
Input Voltage	Input Voltage		Input A			200	μΑ
			Input B			300	
I <sub>IH</sub> High Level Input Current	High Level Input $V_{CC} = Max, V_I = 2.7V$	Clear			20		
		Input A			40	μΑ	
		Input B			60		
Ι <sub>ΙL</sub>	$I_{IL} \qquad \  \  Low \ Level \ Input \\ Current \qquad \qquad V_{CC} = Max, \ V_I = 0.4V$	Low Level Input $V_{CC} = Max, V_I = 0.4V$	Clear			-100	
Current		Input A			-200	μΑ	
			Input B			-300	
lo	Output Drive Current (B Bus Ports Only)	$V_{CC} = Max, V_O = 2.25V$		-30		-112	mA
ICC	Supply Current	V <sub>CC</sub> = Max (Note 1)					mA

Symbol	Parameter	Conditions	From (Input) To (Output)	DM54ALS390		DM74A	LS390	Units
				Min	Max	Min	Max	01113
f <sub>max</sub>	Maximum Clock Frequency	$V_{CC} = 4.5$ to 5.5V,	A to QA					MHz
		$R_{L} = 500, \Omega$ $C_{L} = 50 \text{ pF}$	B to QB					
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output	$T_A = Min \text{ to Max}$ (Note 2)	A to QA					ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output		A to QA					ns
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output		A to QC					ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output		A to QC					ns
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output		B to QB		-			ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output		B to QB					ns
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output		B to QC					ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output		B to QC					ns
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output		B to QD					ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output		B to QD					ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output		Clear to Any Q					ns







1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.

SEMICONDUCTOR CORPORATION. As used herein:

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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0.843-0.870

(21.41-22.10)

1 2 3 4 5 6 7 8

0.040

(1.016)

TYP

0.018 ±0.003

(0.457 ±0.076)

12 11 10 9

+

0.250 ±0.005

(6.350 ±0.127) t

0.130 ±0.005

(3.302 ±0.127)

0.125-0.140 (0.508)

(3.175-3.556)

90°±4

0.145-0.200 (3.683-5.080)

0.020

N16A (REV E)

15 16

+

0.060

(1.524)

0.100 ±0.010

(2.540 ±0.254)

Order Number DM74ALS390N NS Package Number N16A

14 13

NOM

0.065

(1.651)

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